

Silicon NPN Power Transistors

2SC2837

**DESCRIPTION**

- With TO-3PN package
- Complement to type 2SA1186

**APPLICATIONS**

- For audio and general purpose applications

**PINNING**

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

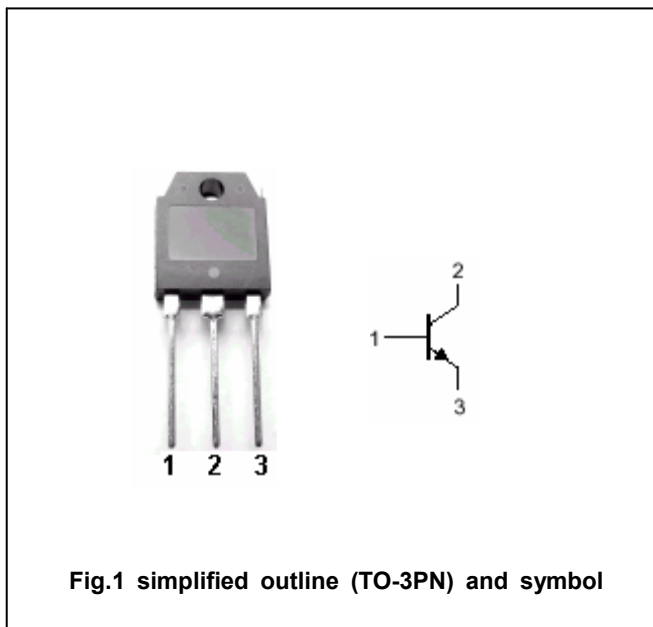


Fig.1 simplified outline (TO-3PN) and symbol

**Absolute maximum ratings (Ta=25°C)**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CBO</sub>	Collector-base voltage	Open emitter	150	V
V <sub>CEO</sub>	Collector-emitter voltage	Open base	150	V
V <sub>EBO</sub>	Emitter-base voltage	Open collector	5	V
I <sub>C</sub>	Collector current		10	A
I <sub>B</sub>	Base current		2	A
P <sub>C</sub>	Collector power dissipation	T <sub>C</sub> =25°C	100	W
T <sub>j</sub>	Junction temperature		150	°C
T <sub>stg</sub>	Storage temperature		-55~150	°C

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## CHARACTERISTICS

T<sub>j</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =25mA ; I <sub>B</sub> =0	150			V
V <sub>CEsat</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =5A ; I <sub>B</sub> =0.5A			2.0	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =150V; I <sub>E</sub> =0			0.1	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =5V; I <sub>C</sub> =0			0.1	mA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =3A ; V <sub>CE</sub> =4V	50			
f <sub>T</sub>	Transition frequency	I <sub>E</sub> =-1A ; V <sub>CE</sub> =12V		70		MHz
C <sub>OB</sub>	Collector output capacitance	f=1MHz; V <sub>CB</sub> =80V		60		pF

## Switching times

t <sub>on</sub>	Turn-on time	I <sub>C</sub> =5A I <sub>B1</sub> =-I <sub>B2</sub> =0.5A V <sub>CC</sub> =60V, R <sub>L</sub> =12Ω		0.2		μs
t <sub>s</sub>	Storage time			1.4		μs
t <sub>f</sub>	Fall time			0.35		μs

◆ h<sub>FE</sub> Classifications

O	P	Y
50-100	70-140	90-180

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PACKAGE OUTLINE

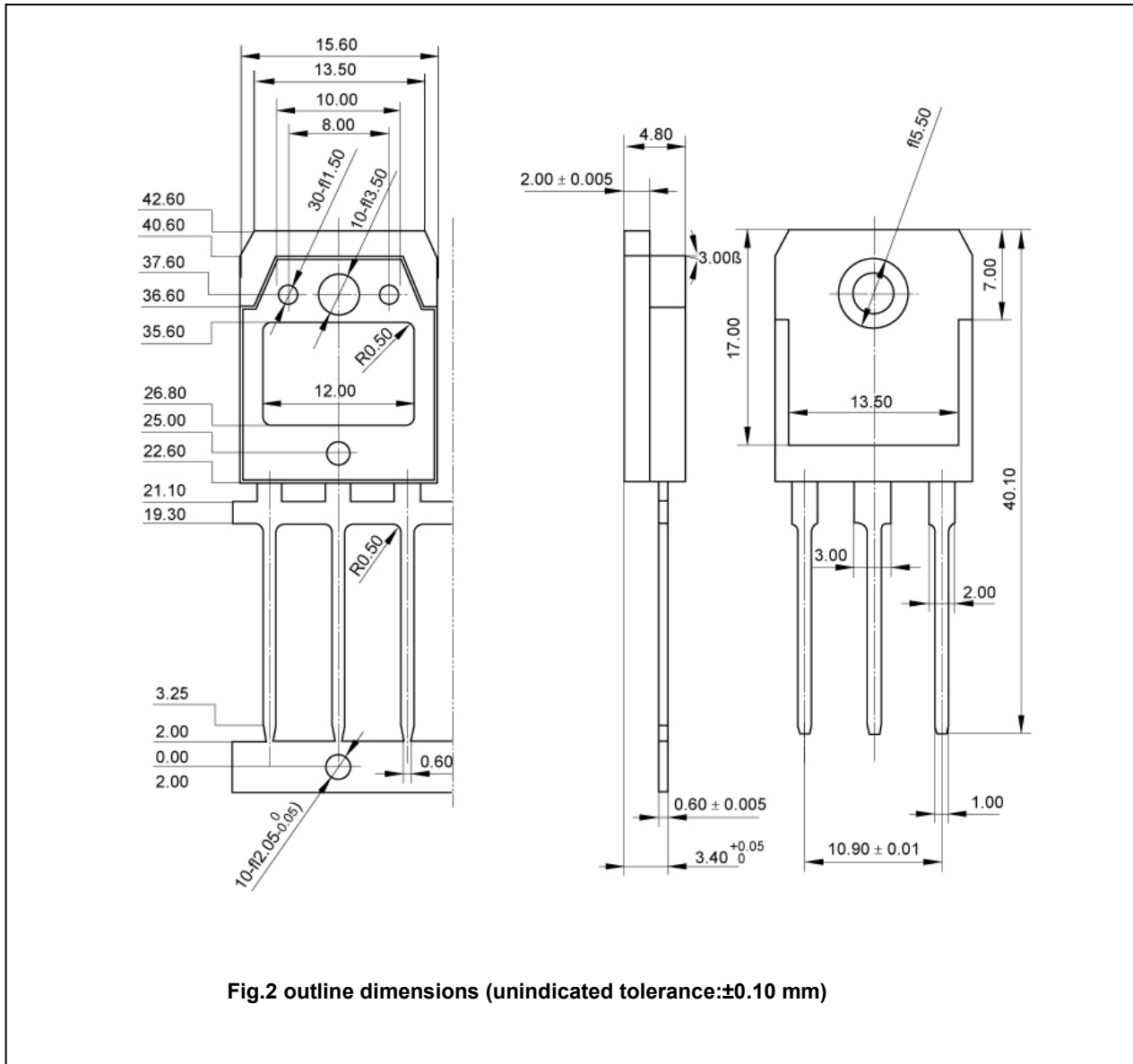


Fig.2 outline dimensions (unindicated tolerance:  $\pm 0.10$  mm)

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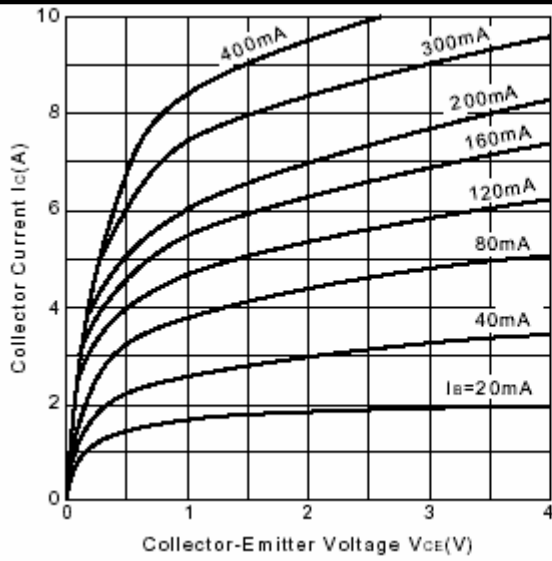


Fig.3 Static Characteristic

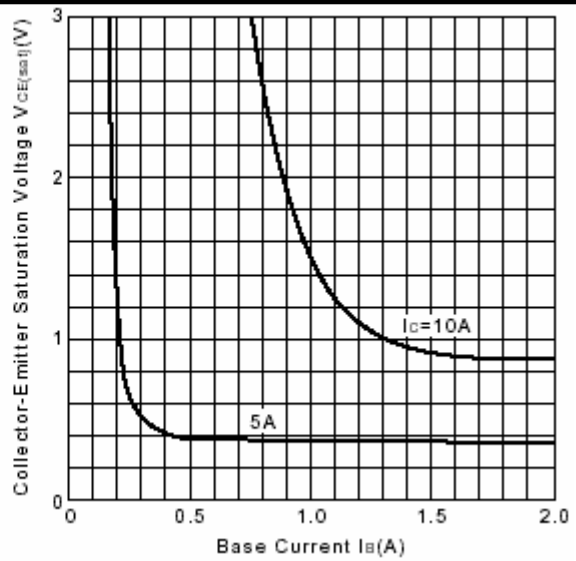


Fig.4  $V_{ce(sat)}-I_b$

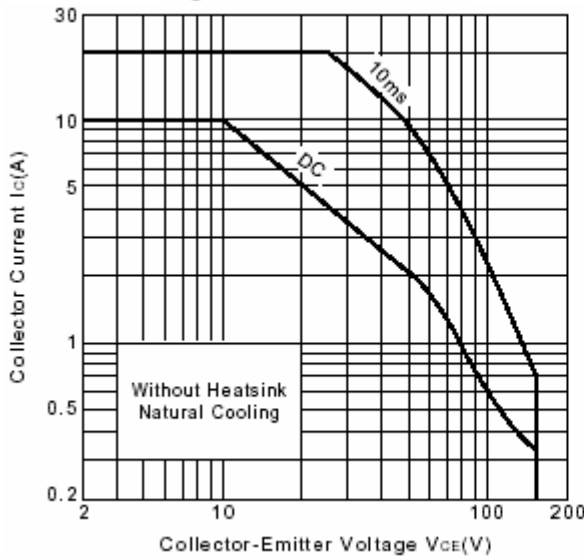


Fig.5 Safe Operating Area

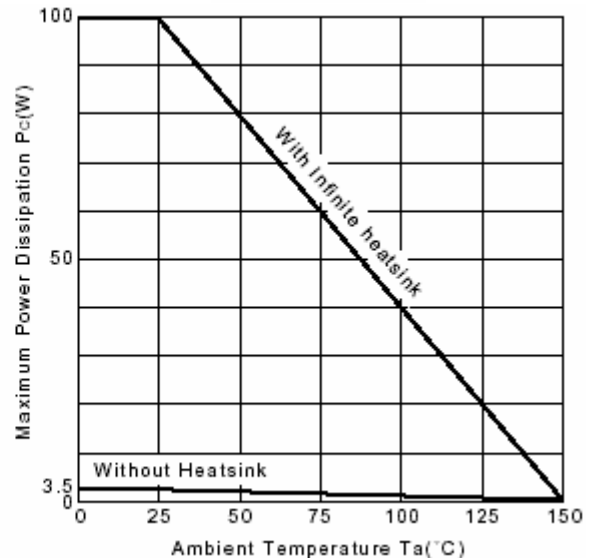


Fig.6 Power Derating

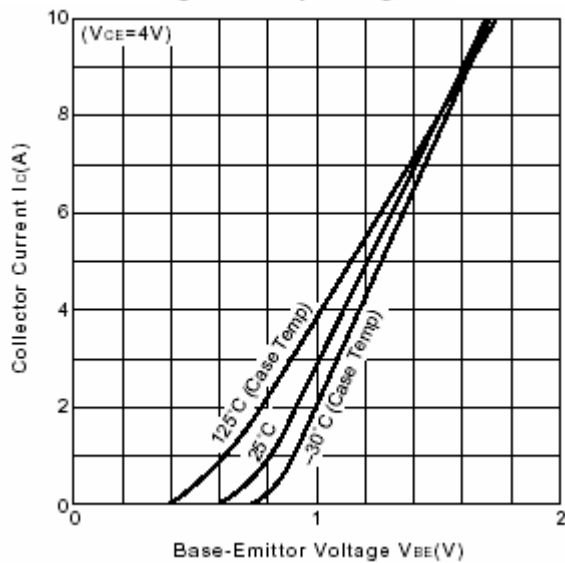


Fig.7  $I_c-V_{be}$

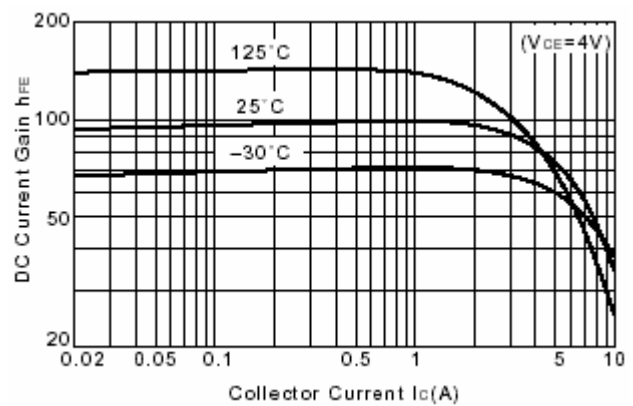


Fig.8 DC current Gain